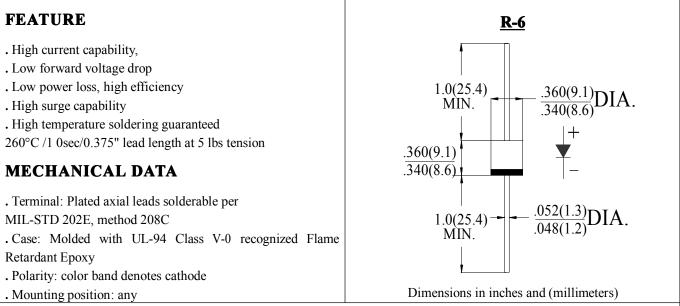


10A4

10.0AMPS SILICON RECTIFIERS



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half-wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated)

Type Number	SYM BOL	10A4	units
Maximum Recurrent Peak Reverse Voltage	VRRM	400	V
Maximum RMS Voltage	V _{RMS}	280	V
Maximum DC blocking Voltage	VDC	400	V
Maximum Average Forward Rectified Current. 375" (9.5mm) lead length @T _A =75°C	IF(AV)	10	А
Peak Forward Surge Current 8.3ms single half sine- wave superimposed on rated load (JEDEC method)	IFSM	400	А
Maximum Forward Voltage at 10.0A DC	V _F	1.0	V
Maximum DC Reverse Current $T_A = 25^{\circ}C$		10.0	μΑ
at rated DC blocking voltage T _A =100°C		200.0	
Typical Junction Capacitance (Note1)	Сл	100	pF
Typical Thermal Resistance (Note2)	R _(JA)	10	°C/W
Storage Temperature	TSTG	-55 to +150	°C
Operation JunctionTemperature	TJ	-55 to +125	°C

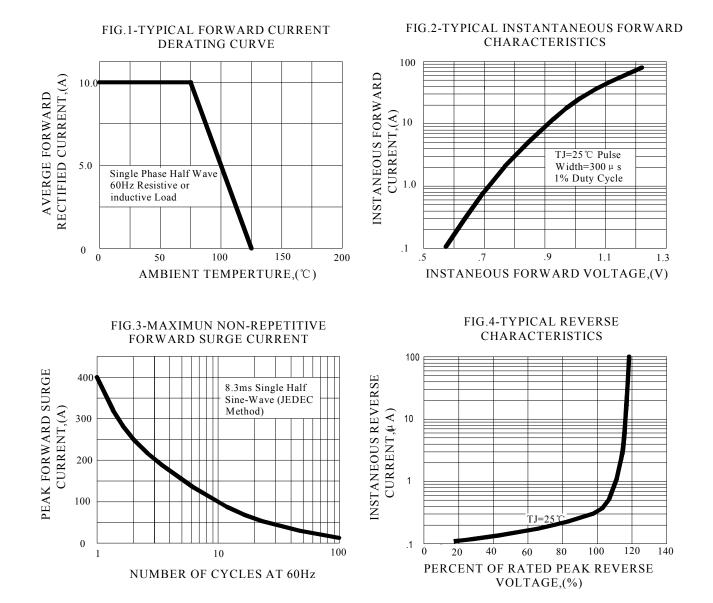
Note:

1. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc

2. Thermal Resistance from Junction to Ambient



RATING AND CHARACTERISTIC CURVES (10A4)



2

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Diodes - General Purpose, Power, Switching category:

Click to view products by Pingwei manufacturer:

Other Similar products are found below :

MCL4151-TR3 MMBD3004S-13-F RD0306T-H RD0506LS-SB-1H RGP30G-E373 DSE010-TR-E BAQ333-TR BAQ335-TR BAQ33-GS18 BAS1602VH6327XT BAV17-TR BAV19-TR BAV301-TR BAW27-TAP HSC285TRF-E NSVBAV23CLT1G NTE525 1SS181-TP 1SS184-TP 1SS193,LF 1SS193-TP 1SS400CST2RA SBAV99LT3G SDAA13 LL4448-GS18 SHN2D02FUTW1T1G LS4150GS18 LS4151GS08 SMMBD7000LT3G FC903-TR-E 1N4449 1N4934-E3/73 1SS226-TP APT100DL60HJ RFUH20TB3S RGP30G-E354 RGP30M-E3/73 D291S45T MCL4151-TR BAS 16-02V H6327 BAS 21U E6327 BAS 28 E6327 BAS33-TAP BAS 70-02V H6327 BAV300-TR BAV303-TR3 BAW27-TR BAW56DWQ-7-F BAW56M3T5G BAW75-TAP